

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

TK380P60Y

• FEATURES

- Static drain-source on-resistance: $R_{DS}(on) \leq 0.38 \Omega$
- · Easy to control Gate switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V_{GS}	Gate-Source Voltage	±30	V
ID	Drain Current-Continuous	9.7	А
IDM	Drain Current-Single Pulsed	38.8	А
PD	Total Dissipation @Tc=25°C	80	W
T _j T _{stg}	Operating Junction And Storage Temperature	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.56	°C/W

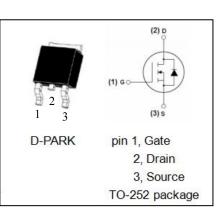
• ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	600		V
V _{GS(th)}	Gate Threshold Voltage	VDS=VGS; I _D = 0.36mA	3	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 4.9A		0.38	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V		±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V		10	μA
V _{SD}	Diode forward voltage	Is= 9.7A, V _{GS} = 0V		1.7	V

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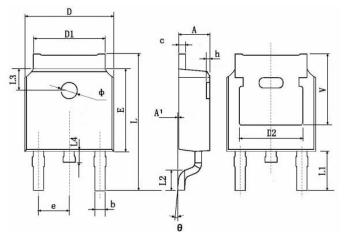


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TO-252 Package Outline



Cumhal	Dimensions	n Millimeters	Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
C	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 TYP.		0.190 TYP.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067
L3	1.600	0.063 0.063		TYP.
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 TYP.		0.211	TYP.

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